Samsung V-NAND SSD 870 EVO

2021 Data Sheet

Revision 1.1





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TECHINCAL SPECIFICATIONS

			Samsung S	SD 870 EVO				
Usage Application	Client PCs							
Interface	SATA 6 Gb/s Interface, compatible with SATA 3 Gb/s & 1.5 interfaces							
Hardware Information	Capacity ¹⁾		250GB	500GB	1TB	2TB	4TB	
	Controller		Samsung MKX Controller					
	NAND Flash Memory		Samsung V-NAND 3bit MLC					
	DRAM Cache Memory		512MB	LPDDR4	1GB LPDDR4	2GB LPDDR4	4GB LPDDR4	
	Dimensions		100x 69.85x 6.8(mm)					
	Form Factor		2.5 inch					
Performance (Up to.) ²⁾	Sequential Read		560 MB/s					
	Sequential Write ³⁾		530 MB/s					
	4KB Ran. Read (QD1)		13,000 IOPS					
	4KB Ran. Write (QD1)		36,000 IOPS					
	4KB Ran. Read (QD32)		98,000 IOPS					
	4KB Ran. Write (QD32)		88,000 IOPS					
Power Consumption ⁴⁾	Idle	DIPM on	30 mW	30 mW	30 mW	35 mW	35 mW	
	Active (Avg.)	Read/Write	2.0W/2.2W	2.0W/2.2W	2.0W/2.5W	2.2W/2.5W	2.2W/2.5W	
	Devslp		2.5 mW	2.5 mW	3.0 mW	4.5 mW	6.5 mW	
	Temp.	Operating			0°C to 70°C		1	
		Non- Operating	-40°C to 85°C					
	Humidity		5% to 95% non-condensing					
Reliability ⁴⁾	Shock	Non- Operating	1,500G, duration: 0.5ms, 3 axis					
	Vibration	Non- Operating	20~2,000Hz, 20G					
	MTBF		1.5 million hours					
Warranty	TBW ⁵⁾		150TB	300TB	600TB	1,200TB	2,400TB	
	Period		5 year limited					
Supporting Features	TRIM (Required OS support), Garbage Collection, S.M.A.R.T							
Data Security		AES 256-bit F	ull Disk Encryp	tion, TCG/Opal '	V2.0, Encrypted	Drive(IEEE1667)	
1) GB: 1GB = 1,000,0	00,000 bytes. A	certain portion of	capacity may be u	sed for system file	and maintenance u	se, thus the actual	available capacity	

1) GB: 1GB = 1,000,000,000 bytes. A certain portion of capacity may be used for system file and maintenance use, thus the actual available capacity may differ from the labeled total capacity.

 Sequential performance measurements are based on CrystalDiskMark v.5.0.2. Random performance measurements are based on IOmeter1.1.0. Performance may vary based on SSD's firmware version, system hardware & configuration. Test system configuration: Intel® Core i7-470K CPU @4.00 GHz, DDR3 1600MHz 8GB, OS-Windows 10 Pro 64bit, Chipset-ASUS Z97 PRO

3) Sequential Write performance measurements are based on Intelligent TurboWrite technology. The sequential performance measurements after Intelligent TurboWrite region are 300MB/s (250/500GB), or 530MB/s (1TB/2TB/4TB).

4) Power consumption is measured with IOmeter1.1.0 version with Intel Core i7-7700K @ 4.2GHz, SAMSUNG DDR4 16GB, Gigabyte GA-Z270X, OS – Windows 10 PRO K x64

 All documented endurance test results are obtained in compliance with JESD218 Standards. Please visit www.jedec.org for detailed information on JESD218 Standards

6) TBW means Total Bytes Written.

7) Please refer to the detailed warranty statement here at <u>http://samsung.com/samsungssd</u>.

8) Warranty provides coverage for the stated time period or the TBW, whichever comes first.

PRODUCT LINEUP

Density	Model Name	Box Contents	Model Code
250GB*			MZ-77E250BW
	MZ-77E250	Samsung SSD 870 EVO 250GB	MZ-77E250B/AM
		Warranty Statement	MZ-77E250B/EU
		warranty Statement	MZ-77E250B/CN
			MZ-77E250B/KR
500GB*	MZ-77E500		MZ-77E500BW
			MZ-77E500B/AM
		Samsung SSD 870 EVO 500GB	MZ-77E500B/EU
		Warranty Statement	MZ-77E500B/CN
			MZ-77E500B/KR
1TB (1,000GB*)	MZ-77E1T0		MZ-77E1T0BW
		Samsung SSD 870 EVO 1TB	MZ-77E1T0B/AM
		Warranty Statement	MZ-77E1T0B/EU
			MZ-77E1T0B/CN
2TB (2,000GB*)	MZ-77E2T0		MZ-77E2T0BW
		Samsung SSD 870 EVO 2TB	MZ-77E2T0B/AM
		Warranty Statement	MZ-77E2T0B/EU
			MZ-77E2T0B/CN
4TB (4,000GB*)			MZ-77E4T0BW
		Samsung SSD 870 EVO 4TB	MZ-77E4T0B/AM
	MZ-77E4T0	Warranty Statement	MZ-77E4T0B/EU
			MZ-77E4T0B/CN

* GB: 1GB = 1,000,000,000 bytes by IDEMA. The actual usable capacity may be less than the labeled capacity. For more information, including but not limited to the warranty provided for this product, please visit www.samsung.com/ssd and www.samsungssd.com.

Revision History

Revision Number	Description	Revision Date
1.0	Initial Release	November 2020
1.1	After TurboWrite performance for $1/2/4$ TB change (500 \rightarrow 530 MB/s)	January 2021

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